

NCE N-Channel Enhancement Mode Power MOSFET

Description

The NCE3420 uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 1.8V. This device is suitable for use as a uni-directional or bi-directional load switch.

General Features

• $V_{DS} = 20V, I_D = 6A$

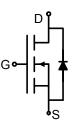
 $R_{DS(ON)}$ < 35m Ω @ V_{GS} =2.5V

 $R_{DS(ON)}$ < 28m Ω @ V_{GS} =4.5V

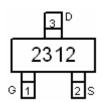
- High Power and current handing capability
- Lead free product is acquired
- Surface Mount Package

Application

- Uni-directional Load switch
- Bi-directional Load switch



Schematic diagram



Marking and pin Assignment



SOT-23 top view

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
3420	NCE3420	SOT-23	Ø180mm	8 mm	3000 units

Absolute Maximum Ratings (T_A=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DS}	20	V
Gate-Source Voltage	V _G s	±10	V
Drain Current-Continuous	I _D	6	Α
Drain Current-Pulsed (Note 1)	I _{DM}	30	Α
Maximum Power Dissipation	P _D	1.25	W
Operating Junction and Storage Temperature Range	T_{J}, T_{STG}	-55 To 150	°C

Thermal Characteristic

Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{ heta JA}$	100	°C/W

Electrical Characteristics (T_A=25 ℃ unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250μA	20	22	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =20V,V _{GS} =0V	-	-	1	μA



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Gate-Body Leakage Current	I _{GSS}	V _{GS} =±10V,V _{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)	<u>.</u>	•		•		
Gate Threshold Voltage	$V_{GS(th)}$	V _{DS} =V _{GS} ,I _D =250μA	0.5	0.7	1.0	V
Drain-Source On-State Resistance	В	V _{GS} =2.5V, I _D =4.0 A	-	27	35	mΩ
	R _{DS(ON)}	V _{GS} =4.5V, I _D =5.0A	-	20	28	mΩ
Forward Transconductance	g _{FS}	V _{DS} =5V,I _D =6A	-	25	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C _{lss}	- V _{DS} =10V,V _{GS} =0V,	-	515	-	PF
Output Capacitance	Coss	F=1.0MHz	-	90	-	PF
Reverse Transfer Capacitance	C _{rss}	F = 1.0IVII 12	-	72	-	PF
Switching Characteristics (Note 4)	·					
Turn-on Delay Time	t _{d(on)}		-	3	-	nS
Turn-on Rise Time	t _r	V_{DD} =10V, R_L =1.7 Ω	-	7.5	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =10V, R_{GEN} =3 Ω	-	20	-	nS
Turn-Off Fall Time	t _f		-	6	-	nS
Total Gate Charge	Q_g		-	12	-	nC
Gate-Source Charge	Q_{gs}	V _{DS} =10V,I _D =6A,V _{GS} =10V	-	1	-	nC
Gate-Drain Charge	Q_{gd}		-	2	-	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =1A	-	-	1.2	V
Diode Forward Current (Note 2)	Is		-	-	6	Α

Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production



Typical Electrical and Thermal Characteristics

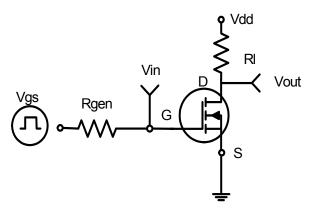


Figure 1:Switching Test Circuit

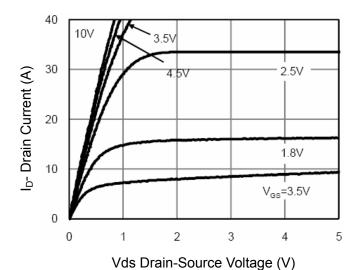


Figure 3 Output Characteristics

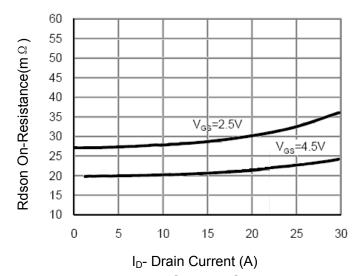


Figure 5 Drain-Source On-Resistance

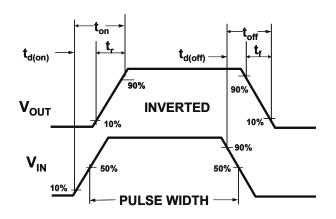
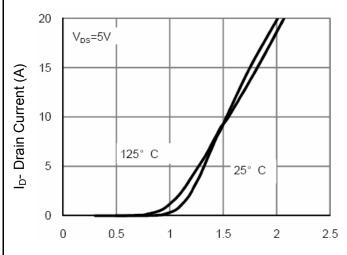


Figure 2:Switching Waveforms



Vgs Gate-Source Voltage (V)

Figure 4 Transfer Characteristics

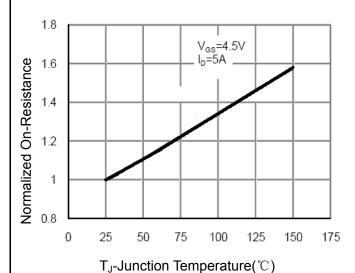


Figure 6 Drain-Source On-Resistance



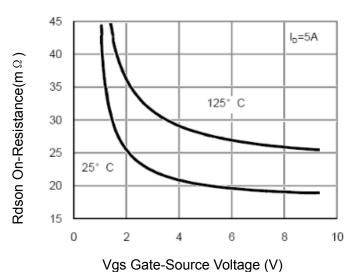


Figure 7 Rdson vs Vgs

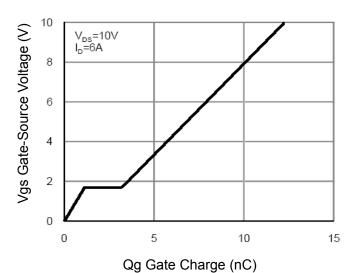


Figure 9 Gate Charge

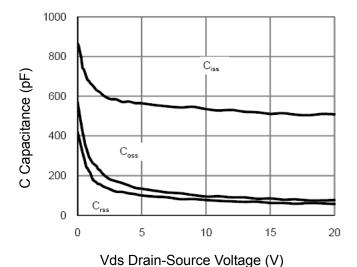


Figure 11 Capacitance vs Vds

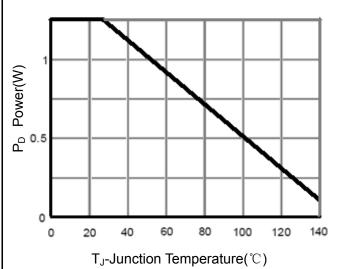


Figure 8 Power Dissipation

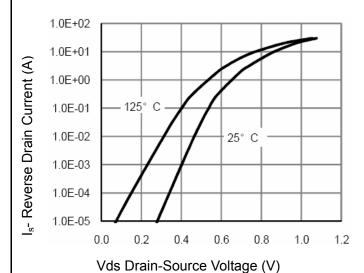
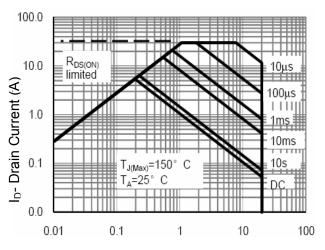


Figure 10 Source- Drain Diode Forward



Vds Drain-Source Voltage (V)
Figure 12 Safe Operation Area

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Pb Free Product

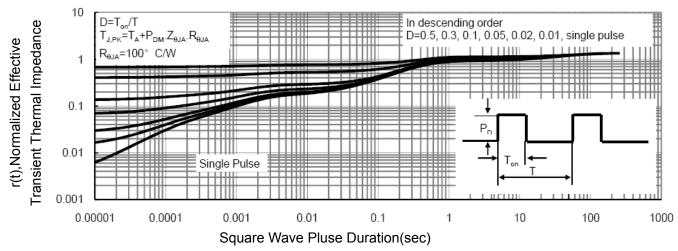
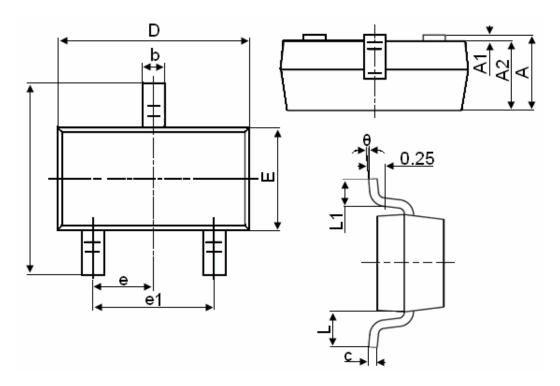


Figure 13 Normalized Maximum Transient Thermal Impedance



SOT-23 Package Information



Symbol	Dimensions in Millimeters				
Symbol	MIN.	MAX.			
Α	0.900	1.150			
A1	0.000	0.100			
A2	0.900	1.050			
b	0.300	0.500			
С	0.080	0.150			
D	2.800	3.000			
Е	1.200	1.400			
E1	2.250	2.550			
е		0.950TYP			
e1	1.800	2.000			
L	0.550REF				
L1	0.300	0.500			
θ	0°	8°			

Notes

- 1. All dimensions are in millimeters.
- 2. Tolerance ±0.10mm (4 mil) unless otherwise specified
- 3. Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 5 mils.
- 4. Dimension L is measured in gauge plane.
- 5. Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.



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